



RS1G260MNTB Information



For Reference Only

Part Number RS1G260MNTB
Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 40V 26A 8HSOP

Package 8-PowerTDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RS1G260MNTB Specifications

Manufacturer Part Number	RS1G260MNTB
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Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	26A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	44nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2988pF @ 20V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	3W (Ta), 35W (Tc)
Rds On (Max) @ Id, Vgs	3.3 mOhm @ 26A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSOP
Package / Case	8-PowerTDFN
	Report errors?

RS1G260MNTB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RS1G260MNTB Payment Methods



















RS1G260MNTB Shipping Methods













If you have any question about RS1G260MNTB, please do not hesitate to contact us!

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